

KSD1020

Audio Frequency Amplifier

Complement to KSB810



1.Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage	30	V
V_{CEO}	Collector-Emitter Voltage	25	V
V _{EBO}	Emitter-Base Voltage	5.0	V
I _C	Collector Current (DC)	700	mA
I _{CP}	* Collector Current (Pulse)	1.0	Α
P _C	Collector Power Dissipation	350	mW
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

^{*} PW≤10ms, Duty Cycle≤50%

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I _{CBO}	Collector Cut-off Current	V_{CB} =30V, I_{E} =0			100	nA
I _{EBO}	Emitter Cut-off Current	V_{EB} =5V, I_{C} =0			100	nA
h _{FE1}	* DC Current Gain	V _{CE} =1V, I _C =100mA	70	200	400	
h_{FE2}		V _{CE} =1V, I _C =700mA	35	140		
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} =6V, I _C =10mA	600	640	700	mV
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =700mA, I _B =70mA		0.2	0.4	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =700mA, I _B =70mA		0.95	1.2	V
C _{ob}	Output Capacitance	V _{CB} =6V, I _E =0, f=1MHz		13	25	pF
f _T	Current Gain Bandwidth Product	V _{CE} =6V, I _C =10mA	50	170		MHz
* Pulso Test DW/250va Duty Cycler 20/						

^{*} Pulse Test: PW≤350μs, Duty Cycle≤ 2%

h_{FE1} Classification

Classification	0	Υ	G
h _{FE1}	70 ~ 140	120 ~ 240	200 ~ 400

Typical Characteristics

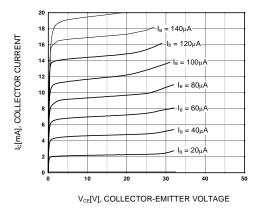


Figure 1. Static Characteristic

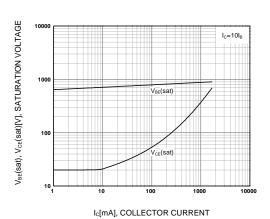


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

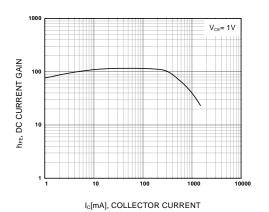


Figure 2. DC current Gain

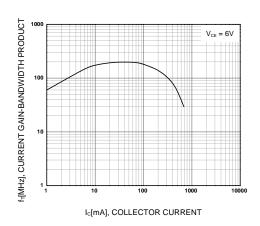
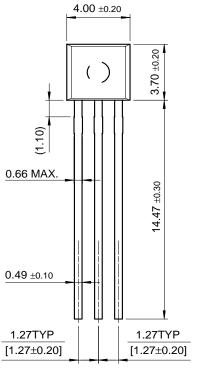
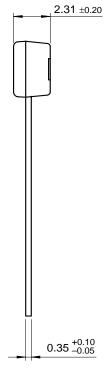


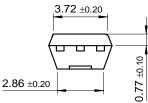
Figure 4. Current Gain-Bandwidth Product

Package Demensions

TO-92S







Dimensions in Millimeters

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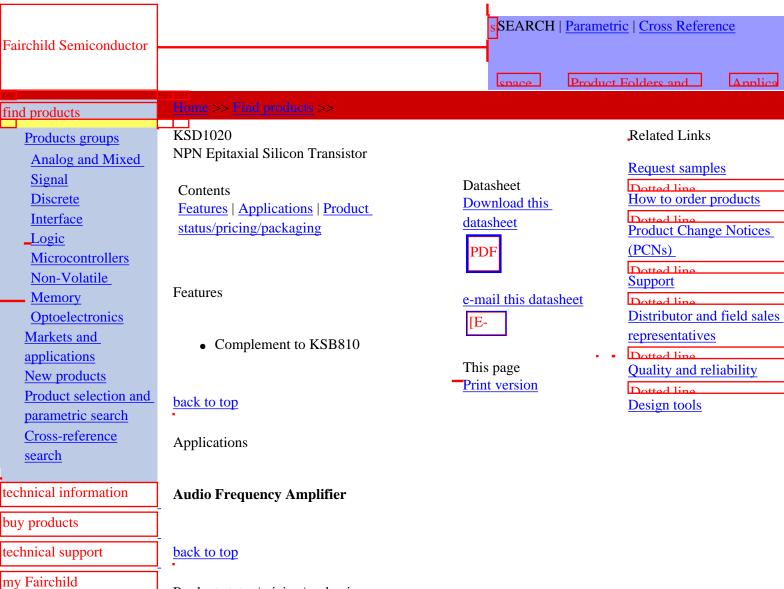
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Datasheet Identification	Product Status	Definition
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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
KSD1020OBU	Full Production	\$0.065	<u>TO-92S</u>	3	BULK
KSD1020OTA	Full Production	\$0.065	<u>TO-92S</u>	3	TAPE REEL
KSD1020YBU	Full Production	\$0.065	<u>TO-92S</u>	3	BULK
KSD1020GBU	Full Production	\$0.065	<u>TO-92S</u>	3	BULK
KSD1020GTA	Full Production	\$0.065	<u>TO-92S</u>	3	TAPE REEL
KSD1020YTA	Full Production	\$0.065	<u>TO-92S</u>	3	TAPE REEL

^{* 1,000} piece Budgetary Pricing

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company

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